

KPT801C

Product code: KPT801C

Manufacturer: Kyosemi Corporation

Features:

- NPN phot transistor
- Ceramic package
- Low leak current

Applications:

- Optical switches
- Optical encoders
- Photo-isolator
- Cameras stroboscopes
- Infrared sensors
- Automatic control apparatus

Half Angle (deg)	120
Package	φ3 ceramic, epoxy lens
Peak sens. wavelength (nm)	800
Photo Current Vce = 5 V	4 (mA) 1000 (lx)
Sensitive Area (mm)	0.64 x 0.64
Typology	Silicon Phototransistors